# SPDT, 1 $\Omega$ R<sub>ON</sub> Switch

The NLAS5123 is a low  $R_{ON}$  SPDT analog switch. This device is designed for low operating voltage, high current switching of speaker output for cell phone applications. It can switch a balanced stereo output. The NLAS5123 can handle a balanced microphone/speaker/ringtone generator in a monophone mode. The device contains a break-before-make (BBM) feature.

#### **Features**

• Single Supply Operation:

1.65 V to 5.5 V V<sub>CC</sub>

- Function Directly from LiON Battery
- $R_{ON}$  Typical = 1.0  $\Omega$  @  $V_{CC}$  = 4.5 V
- Low Static Power
- These are Pb-Free Devices

#### **Typical Applications**

- Cell Phone Speaker/Microphone Switching
- Ringtone-Chip/Amplifier Switching
- Stereo Balanced (Push-Pull) Switching

## Important Information

- Continuous Current Rating Through each Switch ±300 mA
- 1.2 x 1.0 x 0.4P mm 6-Lead Thin DFN Package



## ON Semiconductor®

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WDFN6 MN SUFFIX CASE 506AS



UDFN6 MU SUFFIX CASE 517AA

## **MARKING DIAGRAM**

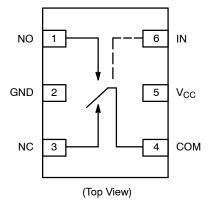


W = Specific Device Code

M = Date Code & Assembly Location

■ = Pb-Free Device

## **PIN ASSIGNMENTS**



## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

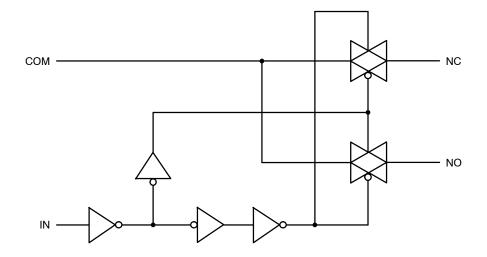


Figure 1. Input Equivalent Circuit

## **PIN DESCRIPTION**

Pin Name	Description
NC, NO, COM	Data Ports
IN	Control Input

#### **TRUTH TABLE**

Control Input	Function
L	NC Connected to COM
Н	NO Connected to COM

H = HIGH Logic Level. L = LOW Logic Level.

## **MAXIMUM RATINGS**

Symbol	Rating	Value	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +6.0	V
V <sub>IS</sub>	Analog Input Voltage (V <sub>NO</sub> , V <sub>NC</sub> , or V <sub>COM</sub> )	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>IN</sub>	Digital Select Input Voltage	-0.5 to +6.0	V
I <sub>anl1</sub>	Continuous DC Current from COM to NC/NO	±300	mA
I <sub>anl-pk1</sub>	Peak Current from COM to NC/NO, 10 Duty Cycles (Note 1)	±500	mA
I <sub>clmp</sub>	Continuous DC Current into COM/NC/NO with respect to V <sub>CC</sub> or GND	±100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Defined as 10% ON, 90% off duty cycle.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Rating	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage		1.65	5.5	V
V <sub>IS</sub>	Analog Input Voltage (NC, NO, COM)		0	V <sub>CC</sub>	V
V <sub>IN</sub>	Digital Select Input Voltage (IN)		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range		-40	85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Time, SELECT	V <sub>CC</sub> = 3.0 V V <sub>CC</sub> = 5.5 V		20 10	ns/V

#### DC ELECTRICAL CHARACTERISTICS

			v <sub>cc</sub>	Ţ	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°0	C to +85°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage		2.7 4.5				2.0 2.4		V
V <sub>IL</sub>	LOW Level Input Voltage		2.7 4.5					0.6 0.8	٧
I <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0-5.5			±0.1		±1	μА
I <sub>OFF</sub>	OFF State Leakage Current (Note 7)	$0 \le NO, NC, COM \le V_{CC}$	5.5	-2.0		+2.0		±20	nA
I <sub>ON</sub>	ON State Leakage Current (Note 7)	$0 \le NO, NC, COM \le V_{CC}$	5.5	-4.0		+4.0		±40	nA
R <sub>ON</sub>	Switch On Resistance (Note 2)	I <sub>O</sub> = 100 mA, V <sub>IS</sub> = 0 V to V <sub>CC</sub>	2.7			1.7		2.0	Ω
		I <sub>O</sub> = 100 mA, V <sub>IS</sub> = 0 V to V <sub>CC</sub>	4.5			1.0		1.2	
I <sub>CC</sub>	Quiescent Supply Current All Channels ON or OFF	V <sub>IN</sub> = V <sub>CC</sub> or GND, I <sub>OUT</sub> = 0	5.5			0.5		1.0	μΑ

#### **Analog Signal Range**

ΔR <sub>ON</sub>	On Resistance Match Between Channels (Notes 2, 3, 4)	I <sub>A</sub> = 100 mA, V <sub>IS</sub> = 1.5 V I <sub>A</sub> = 100 mA, V <sub>IS</sub> = 2.5 V	2.7 4.5	0.15 0.12		0.15	Ω
R <sub>flat</sub>	On Resistance Flatness (Notes 2, 3, 5)	$I_A = 100 \text{ mA},$ $V_{IS} = 0 \text{ V to } V_{CC}$ $I_A = 100 \text{ mA},$	2.7 4.5	0.4		0.4	Ω
		$V_{IS} = 0 \text{ V to } V_{CC}$					

<sup>2.</sup> Measured by the voltage drop between NC/NO and COM pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (NO, NC, COM).

Parameter is characterized but not tested in production.
 ΔR<sub>ON</sub> = R<sub>ON</sub> max – R<sub>ON</sub> min measured at identical V<sub>CC</sub>, temperature and voltage levels.
 Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.

<sup>6.</sup> Guaranteed by Design.

<sup>7.</sup> This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

#### **AC ELECTRICAL CHARACTERISTICS**

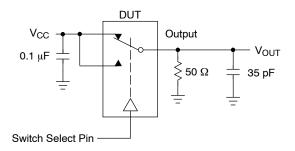
			v <sub>cc</sub>	T,	գ = +25°	C	T <sub>A</sub> = -40°0	C to +85°C		Figure
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Unit	#
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation Delay Bus-to-Bus (Note 9)	$V_{IN} = V_{IH}$ or $V_{IL}$	2.7 4.5			2.0 0.3			ns	
t <sub>ON</sub>	Output Enable Time Turn On Time (COM to NO or NC)	$\begin{aligned} &V_{IS} = 1.5 \text{ V}, \\ &R_L = 50 \ \Omega, C_L = 35 \text{ pF} \\ &V_{IS} = 3.0 \text{ V}, \\ &R_L = 50 \ \Omega, C_L = 35 \text{ pF} \end{aligned}$	2.7 4.5			30 20		35 25	ns	3, 4
t <sub>OFF</sub>	Output Disable Time Turn Off Time (COM to NO, NC)	$\begin{aligned} &V_{ S} = 1.5\text{V}, \\ &R_L = 50 \ \Omega, \ C_L = 35 \ \text{pF} \\ &V_{ S} = 3.0 \ \text{V}, \\ &R_L = 50 \ \Omega, \ C_L = 35 \ \text{pF} \end{aligned}$	2.7 4.5			20 15		25 20	ns	3, 4
t <sub>BBM</sub>	Break Before Make Time (Note 8)	$V_{IS} = 1.5V$ , $R_L = 50 \ \Omega$ , $C_L = 35 \ pF$	2.7	0.5			0.5		ns	2
			4.5	0.5			0.5			
Q	Charge Injection (Note 8)	$C_L$ = 1.0 nF, $V_{GEN}$ = 0 V $R_{GEN}$ = 0 $\Omega$	2.7 4.5		26 48				pC	6
O <sub>IRR</sub>	Off Isolation (Note 10)	$R_L = 50 \Omega$ f = 1.0 MHz	2.7 – 5.5		-62				dB	5
X <sub>talk</sub>	Crosstalk	$R_L = 50 \Omega$ f = 1.0 MHz	2.7 – 5.5		-70				dB	7
BW	-3 dB Bandwidth	R <sub>L</sub> = 50 Ω	2.7 – 5.5		55				MHz	8
THD	Total Harmonic Distortion (Note 8)	$R_L = 600 \Omega$ 0.5 $V_{P-P}$ f = 20 Hz to 20 kHz	2.7 – 5.5		0.012				%	9

## **CAPACITANCE** (Note 11)

Symbol	Parameter	Test Conditions	Тур	Max	Unit
C <sub>IN</sub>	Select Pin Input Capacitance	V <sub>CC</sub> = 0 V, f = 1 MHz	2.0		pF
C <sub>NC/NO</sub>	NC, NO Port Off Capacitance	V <sub>CC</sub> = 4.5 V, f = 1 MHz	20		pF
C <sub>COM</sub>	COM Port Capacitance when Switch is Enabled	V <sub>CC</sub> = 4.5 V, f = 1 MHz	55		pF

<sup>11.</sup> T<sub>A</sub> = +25°C, f = 1 MHz, Capacitance is characterized but not tested in production.

Guaranteed by Design.
 This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).
 Off Isolation = 20 log<sub>10</sub> [V<sub>COM</sub>/V<sub>NO,NC</sub>].



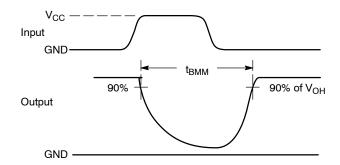
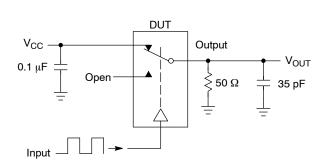


Figure 2. t<sub>BBM</sub> (Time Break-Before-Make)



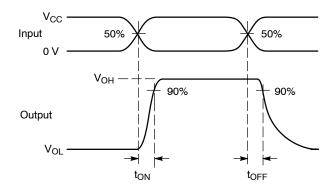
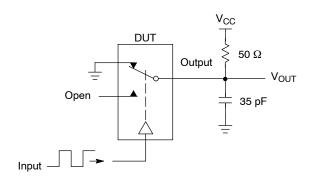


Figure 3. t<sub>ON</sub>/t<sub>OFF</sub>



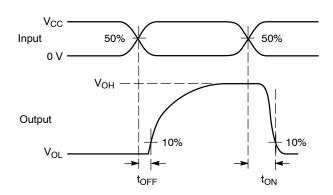
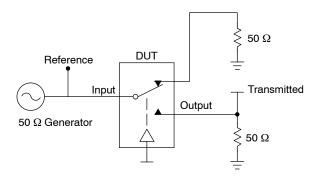


Figure 4. t<sub>ON</sub>/t<sub>OFF</sub>



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch.  $V_{\rm ISO}$ , Bandwidth and  $V_{\rm ONL}$  are independent of the input signal direction.

$$\begin{split} &V_{ISO} = \text{Off Channel Isolation} = 20 \text{ Log} \left( \frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \\ &V_{ONL} = \text{On Channel Loss} = 20 \text{ Log} \left( \frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below  $V_{ONL}$ 

 $V_{CT}$  = Use  $V_{ISO}$  setup and test to all other switch analog input/outputs terminated with 50  $\Omega$ 

Figure 5. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V<sub>ONL</sub>

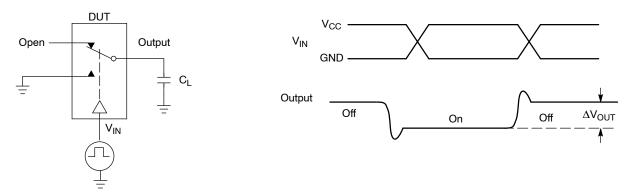
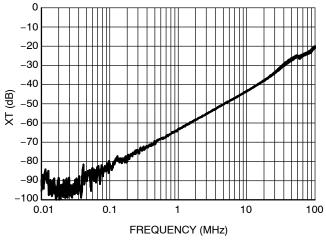


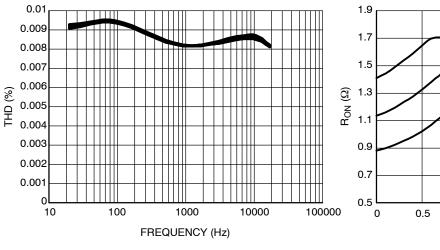
Figure 6. Charge Injection: (Q)



-0.5
-1
-1.5
-1
-1.5
-2
M
-2.5
-3
-3.5
-4
-4.5
0.01
0.1
1
10
100
FREQUENCY (MHz)

Figure 7. Cross Talk vs. Frequency
@ V<sub>CC</sub> = 4.5 V

Figure 8. Bandwidth vs. Frequency



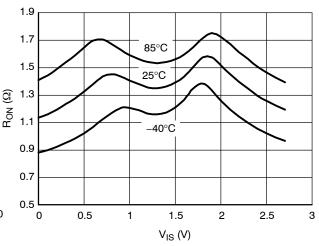
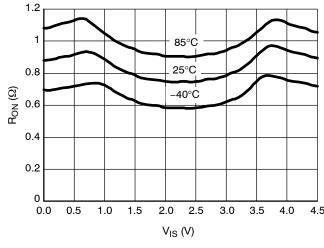


Figure 9. Total Harmonic Distortion

Figure 10. On–Resistance vs. Input Voltage  $@V_{CC} = 2.7 \text{ V}$ 



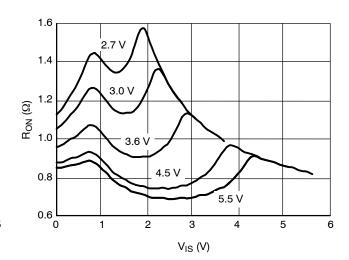


Figure 11. On–Resistance vs. Input Voltage @ V<sub>CC</sub> = 4.5 V

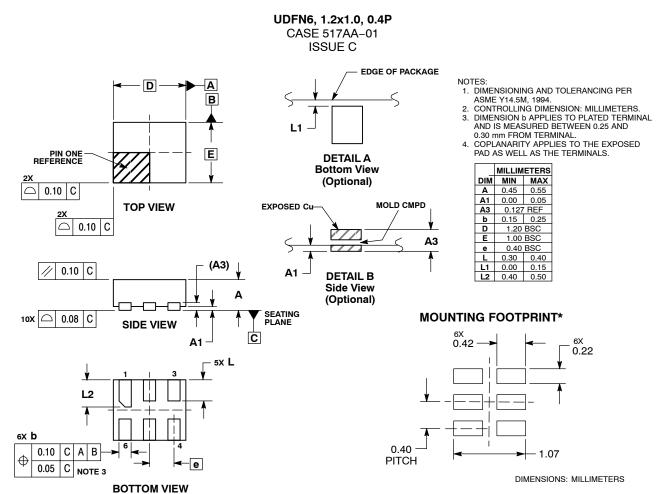
Figure 12. On-Resistance vs. Input Voltage

## **DEVICE ORDERING INFORMATION**

		Devi	ce Nomenc				
Device Order Number	Circuit Indicator	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type	Tape & Reel Size <sup>†</sup>
NLAS5123MNR2G	NL	AS	5123	MN	2	WDFN6 (Pb-Free)	3000 / Tape & Reel
NLAS5123MUR2G	NL	AS	5123	MU	2	UDFN6 (Pb-Free)	3000 / Tape & Reel

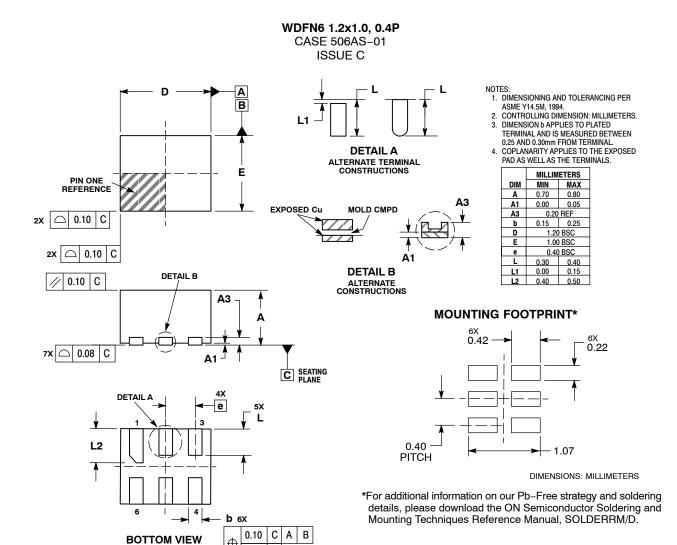
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## PACKAGE DIMENSIONS



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS



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